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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/517,589	03/03/2000	Masami Hatori	Q56793 5455		
7590 11/28/2003			EXAMINER		
	Zinn Macpeak & Seas	RODRIGUEZ, ARMANDO			
2100 Pennsylva Washington, De	nia Avenue N W	ART UNIT	PAPER NUMBER		
washington, D	C 20037		2828		
		•	DATE MAH ED. 11/29/2002		

Please find below and/or attached an Office communication concerning this application or proceeding.

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,		Applicat	ion No.	Applicant(s)	oiv _			
I_2		09/517,5	589	HATORI ET AL.	•			
	Office Action Summary	Examine	er	Art Unit				
			Rodriguez	2828				
Period fo	The MAILING DATE of this communic or Reply	ation appears on th	ne cover sheet with the	correspondence ad	ddress			
THE N - Exter after - If the - If NO - Failur - Any r	ORTENED STATUTORY PERIOD FO MAILING DATE OF THIS COMMUNIC nsions of time may be available under the provisions of SIX (6) MONTHS from the mailing date of this communic period for reply specified above is less than thirty (30) period for reply is specified above, the maximum stature to reply within the set or extended period for reply with eply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	ATION. 37 CFR 1.136(a). In no e nication. days, a reply within the statory period will apply and all, by statute, cause the ap	event, however, may a reply be to atutory minimum of thirty (30) da will expire SIX (6) MONTHS from application to become ABANDON	imely filed ys will be considered time the mailing date of this of ED (35 U.S.C. § 133).	ly. communication.			
1)🖂	Responsive to communication(s) filed	on <u>28 October 20</u>	<u>03</u> .					
2a) <u></u>	This action is FINAL . 2b)⊠ This action is r	non-final.					
3)□								
Dispositi	on of Claims			0				
4)🖂	Claim(s) 1-32 is/are pending in the ap	plication.		Ro	A Company			
· ·	4a) Of the above claim(s) is/are		onsideration.	Jane				
5)	 ✓ Claim(s) 1-32 is/are pending in the application. ✓ 4a) Of the above claim(s) is/are withdrawn from consideration. ✓ Claim(s) is/are allowed. ✓ Claim(s) 1-32 is/are rejected. 							
6)⊠	Claim(s) 1-32 is/are rejected.							
7)								
8)[Claim(s) are subject to restriction	on and/or election	requirement.					
Applicati	on Papers							
9)[The specification is objected to by the	Examiner.						
10)[10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.							
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11) 🔲	The oath or declaration is objected to t	by the Examiner. N	lote the attached Offic	e Action or form P	TO-152.			
Priority u	ınder 35 U.S.C. §§ 119 and 120							
a)[13)	Acknowledgment is made of a claim for All b) Some * c) None of: 1. Certified copies of the priority do 2. Certified copies of the priority do 3. Copies of the certified copies of application from the International Cee the attached detailed Office action acknowledgment is made of a claim for ince a specific reference was included of CFR 1.78. 1. The translation of the foreign languacknowledgment is made of a claim for eference was included in the first sente	ocuments have be ocuments have be the priority documents Bureau (PCT Rufor a list of the cerdomestic priority unin the first sentence domestic priority and domestic priority and domestic priority and domestic priority and the first sentence domestic priority and the priority an	en received. en received in Applica nents have been receivalle 17.2(a)). tified copies not receivander 35 U.S.C. § 119 te of the specification of application has been receivander 35 U.S.C. §§ 12	tion No yed in this National red. (e) (to a provisional or in an Application sceived. 0 and/or 121 since	al application) Data Sheet. a specific			
	t(s) e of References Cited (PTO-892)		4) Interview Summar	v (PTO-413) Paner No	(2)			
2) Notic	e of References Cited (F10-692) e of Draftsperson's Patent Drawing Review (PT0 mation Disclosure Statement(s) (PT0-1449) Pap		5) Notice of Informal 6) Other:					

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DETAILED ACTION

Response to Arguments

Applicant's arguments, see response, filed October 28, 2003, with respect to the rejection(s)of claim(s) 1-3,5-24 under 35 U.S.C. 102 (b) and claims 4,25-32 under 35 U.S.C. 103 based on the Sonoda reference have been fully considered and are persuasive. Therefore, the rejection has been withdrawn. However, upon further consideration, a new ground(s) of rejection is made in view of the newly found art, which discloses the bulk shape nonlinear crystal.

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 24 is rejected under 35 U.S.C. 112, second paragraph, as being incomplete for omitting essential elements, such omission amounting to a gap between the elements. See MPEP § 2172.01. The omitted elements are: no structure has been recited for the laser to provide the recited limitation of "single-peak spatial mode".

Regarding claim 24,

The claim language does not disclose any particular structural difference between the recited semiconductor of claim 24 and the semiconductor laser of the prior art reference, thereby both lasers will provide the recited limitation of "single-peak spatial mode".

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Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1,3,7,18-24,29,30,31 are rejected under 35 U.S.C. 102(b) as being anticipated by Yamamoto et al (PN 5,452,312).

Regarding claims 1,3,7,18-20,24,

Figure 9 illustrates a second harmonic generating laser device having a semiconductor laser (21) emitting a fundamental wave (P1), an optical transmitting filter (50) and a light wavelength converting device (22) formed from a substrate having nonlinear optical effects, as shown the filter is located between the laser and the wavelength conversion device. The wavelength conversion device includes a mirror (61) for reflecting the fundamental wavelength, as described in the abstract and column 11 lines 5-37. In column 13 lines 45-68 to column 14 lines 1-19, Yamamoto et al discloses that a bulk-type wavelength conversion may used within the second harmonic generating laser device.

Regarding claim 21,

In column 13 lines 45-68 to column 14 lines 1-19, Yamamoto et al discloses a bulk-type wavelength conversion composed of LiTaO₃.

Regarding claim 22,29,30,31,

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In column 13 lines 45-68 to column 14 lines 1-19, Yamamoto et al discloses a bulk-type wavelength conversion having polarization inversion layers (3), which extend to the end surfaces of the crystal.

Regarding claim 23,

In column 13 lines 45-68, Yamamoto et al discloses using semiconductor laser of 600 mW.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 2,4,5,6,8-17 and 25-28 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sonoda (JP10254001) in view of Yamamoto et al and Urakami et al.

In figure 1 Sonoda illustrates a semiconductor laser (10), a wavelength conversion waveguide (15) and a filter (14). The waveguide and the laser form an external resonant cavity by having a high reflective coating, which reflects the laser light and outputs second harmonic light. The band pass filter will provide wavelength selection.

Sonoda is silent as to using a bulk-shaped wavelength conversion crystal.

Figure 9 Yamamoto et al illustrates a second harmonic generating laser device having a semiconductor laser (21) emitting a fundamental wave (P1), an optical transmitting filter (50) and a light wavelength converting device (22) formed from a

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substrate having nonlinear optical effects, as shown the filter is located between the laser and the wavelength conversion device. The wavelength conversion device includes a mirror (61) for reflecting the fundamental wavelength, as described in the abstract and column 11 lines 5-37. In column 13 lines 45-68 to column 14 lines 1-19, Yamamoto et al discloses that a bulk-type wavelength conversion may used within the second harmonic generating laser device.

Therefore, it would have been obvious to a person having ordinary skill in the art to use a bulk-type wavelength conversion crystal within the laser device of Sonoda as suggested and taught by Yamamoto because it would provide an efficient wavelength conversion when using a high power laser.

Regarding claim 2,

Figure 7 of Sonoda illustrates an embodiment using a beam splitter (82) for separating the beam.

Regarding claims 4,8,

In figure 1 Yamamoto et al illustrates separating the fundamental beam from the second harmonic beam via mirror (61) and in column 9 lines 45-55 describes modulating the signal.

Therefore, it would have been obvious to person having ordinary skill in the art to provide an optical arrangement for separating the output signal because it would allow for returning the fundamental wave back into the nonlinear crystal for harmonic generation as described by Yamamoto et al.

Regarding claim 5,

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Figure 9 of Sonoda illustrates an embodiment providing a backward light, which is reflected by mirror (85) and fed back to the laser.

Regarding claim 6,15,

Figure 10 of Sonoda illustrates a grating (90), which reflects part of the beam and selects the wavelength.

Regarding claim 9,

Figure 18 of Sonoda illustrates a grating (92) reflecting a backward light from the laser and selects the wavelength.

Regarding claims 10,11,12,13,14,

Sonoda does disclose a birefringent band pass filter (14), which may be a thin film type filter (91) formed on the surface of laser 10, see figure 11 of Sonoda.

Regarding claim 16,17,

Figure 20 of Sonoda illustrates fiber grating (23) providing reflection and wavelength selection, where the light beam is converged into the fiber via lens (22).

Regarding claims 25-27,

Sonoda does not disclose intensity modulation of the output signal.

Yamamoto et al discloses modulation of signal but does not disclose modulating the signal as it is exited from the nonlinear crystal.

However, intensity modulation of laser signals is well known in the laser art as documented in 1992 by Urakami et al, described in column 3 lines 49-68 to column 4 line 4 and illustrated in figures 1-4.

Regarding claim 28,

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In column 1 lines 7-20, Yamamoto et al discloses using the laser device for optical information processing, which requires recording.

Therefore, it would have been obvious to use claimed wavelength conversion device within an optical information system, as suggested by Yamamoto et al.

Regarding claim 32,

In column 13 lines 45-68 to column 14 lines 1-19, Yamamoto et al discloses a bulk-type wavelength conversion having polarization inversion layers (3), which extend to the end surfaces of the crystal.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Armando Rodriguez whose telephone number is (703) 308-6218. The examiner can normally be reached on 10-hour day / M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Paul Ip can be reached on (703) 308-3098. The fax phone number for the organization where this application or proceeding is assigned is (703) 308-7722.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-

4881.

Afmando Rodriguez

Examiner Art Unit 2828

Paul Ip Supervisor Art Unit 2828

AR/PI